### **Constant Voltage / Constant Current Secondary-Side Controller**

### Description

The NCS1002A is a performance upgrade from the NCS1002 focused on reducing power consumption in applications that require more efficient operation. It is a highly integrated solution for Switching Mode Power Supply (SMPS) applications requiring a dual control loop to perform Constant Voltage (CV) and Constant Current (CC) regulation. The NCS1002A integrates a 2.5 V voltage reference and two precision op amps. The voltage reference, along with Op Amp 1, is the core of the voltage control-loop. Op Amp 2 is an independent, uncommitted amplifier specifically designed for the current control. Key external components needed to complete the two control loops are: (a) A resistor divider that senses the output of the power supply (battery charger) and fixes the voltage regulation set point at the specified value. (b) A sense resistor that feeds the current sensing circuit with a voltage proportional to the DC output current. This resistor determines the current regulation set point and must be adequately rated in terms of power dissipation. The NCS1002A comes in a small 8-pin SOIC package and is ideal for space-shrunk applications such as battery chargers.

### Features

- Low Input Offset Voltage: 0.5 mV, Typ
- Input Common-Mode Range includes Ground
- Low Quiescent Current: 75  $\mu$ A per Op Amp at V<sub>CC</sub> = 5 V
- Large Output Voltage Swing
- Wide Power Supply Range: 3 V to 36 V
- High ESD Protection: 2 kV
- This is a Pb–Free Device

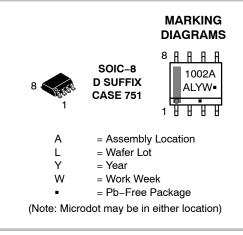
### **Typical Applications**

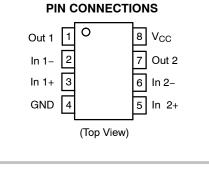
- Battery Chargers
- Switch Mode Power Supplies

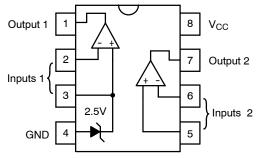


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### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 8 of this data sheet.

### MAXIMUM RATINGS

Parameter	Symbol	Rating	Unit
Supply Voltage (V <sub>CC</sub> to GND) (Operating Range V <sub>CC</sub> = 3 V to 36 V)	V <sub>CC</sub>	36	V
Differential Input Voltage	V <sub>id</sub>	36	V
Input Voltage	Vi	–0.3 to +36	V
ESD Protection Voltage at Pin Human Body Model	V <sub>ESD</sub>	2000	V
Maximum Junction Temperature	TJ	150	°C
Specification Temperature Range (T <sub>min</sub> to T <sub>max</sub> )	T <sub>A</sub>	-40 to +105	°C
Operating Free-Air Temperature Range	T <sub>oper</sub>	–55 to +125	°C
Storage Temperature Range	T <sub>stg</sub>	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS

Parameter		Symbol	Rating	Unit
Thermal Resistance	Junction-to-Ambient	$R_{\thetaJA}$	175	°C/W

### **ELECTRICAL CHARACTERISTICS**

Symbol	Characteristics	Conditions	Min	Тур	Max	Unit
I <sub>CC</sub>	Total Supply Current, excluding current in the Voltag load; –40 $\leq$ T_A $\leq$ +105°C	ge Reference V <sub>CC</sub> = 5 V, no		0.15	0.25	mA
Icc	Total Supply Current, excluding Current in the Voltage Reference V_{CC} = 30 V, no load; -40 $\leq T_A \leq$ +105°C			0.2	0.3	mA

## OP AMP 1 (OP AMP WITH NONINVERTING INPUT CONNECTED TO THE INTERNAL $v_{ref}$ (V $_{CC}$ = 5 V, T $_{A}$ = 25°C unless otherwise noted)

V <sub>IO</sub>	Input Offset Voltage	$T_A = 25^{\circ}C$			2.0	mV
		$-40 \le T_A \le +105^{\circ}C$			3.0	mV
DVIO	Input Offset Voltage Drift (-40 $\leq T_A \leq +105^{\circ}C$ )			7.0		μV/°C
I <sub>IB</sub>	Input Bias Current (Inverting Input Only)			20	150	nA
AVD	Large Signal Voltage Gain (V_{CC} = 15 V, R_L = 2 k\Omega, V_{ICM} = 0 V)			100		V/mV
PSRR	Power Supply Rejection (V <sub>CC</sub> = 5.0 V to 30 V, V <sub>OUT</sub>	· = 2 V)	80	100		dB
ISOURCE	Output Source Current (V <sub>CC</sub> = 15 V, V <sub>OUT</sub> = 2.0 V, $V_{id}$ = 1 V)		20	40		mA
Ι <sub>Ο</sub>	Short Circuit to GND (V <sub>CC</sub> = 15 V)			40	60	mA
I <sub>SINK</sub>	Output Current Sink (V <sub>id</sub> = -1 V)	V <sub>CC</sub> = +15 V, V <sub>OUT</sub> = 0.2 V (Note 1)	1	10		mA
		$V_{CC}$ = +15 V, $V_{OUT}$ = 2 V	10	20		mA
V <sub>OH</sub>	Output Voltage Swing, High (V <sub>CC</sub> = 30 V)	$R_L = 2 k\Omega, T_A = 25^{\circ}C$	26	27		V
		$-40 \le T_A \le +105^{\circ}C$	26			1
		$R_L = 10 \text{ k}\Omega, T_A = 25^{\circ}C$	27	28		1
		$-40 \le T_A \le +105^{\circ}C$	27			1
V <sub>OL</sub>	Output Voltage Swing, Low	$R_L = 10 \text{ k}\Omega, T_A = 25^{\circ}C$		5.0	50	mV
SR	Slew Rate (AV = +1, V <sub>i</sub> = 0.5 V to 2 V, V <sub>CC</sub> = 15 V, R <sub>L</sub> = 2 k\Omega, C <sub>L</sub> = 100 pF)		0.2	0.4		V/μs
GBP	Gain Bandwidth Product (V <sub>CC</sub> = 30 V, AV = +1, (Note 1) R <sub>L</sub> = 2 k $\Omega$ , C <sub>L</sub> = 100 pF, f = 100 kHz, V <sub>IN</sub> = 10 mV <sub>PP</sub> )		0.5	0.9		MHz
THD	Total Harmonic Distortion (f = 1 kHz, AV = 10, $R_L = 2 k\Omega$ , $V_{CC} = 30 V$ , $V_{OUT} = 2 V_{PP}$ )			0.08		%

OP AMP 2 (INDEPENDENT OP AMP) ( $V_{CC}$  = 5.0 V,  $T_A$  = 25°C unless otherwise noted)

V <sub>IO</sub>	Input Offset Voltage	T <sub>A</sub> = 25°C		0.5	2.0	mV
		$-40 \le T_A \le +105^{\circ}C$			3.0	
DV <sub>IO</sub>	Input Offset Voltage Drift (-40 $\leq T_A \leq +105^{\circ}C$ )			7.0		μV/°C
I <sub>IO</sub>	Input Offset Current	$T_A = 25^{\circ}C$		2.0	75	nA
		$-40 \le T_A \le +105^{\circ}C$			150	
Ι <sub>Β</sub>	Input Bias Current	$T_A = 25^{\circ}C$		20	150	nA
		$-40 \le T_A \le +105^{\circ}C$			200	
AVD	Large Signal Voltage Gain ( $V_{CC} = 15$ V,	$T_A = 25^{\circ}C$	50	100		V/mV
	$R_L = 2 k\Omega, V_{OUT} = 1.4 V \text{ to } 11.4 V$	$-40 \le T_A \le +105^{\circ}C$	25			
PSRR	Power Supply Rejection ( $V_{CC}$ = 5 V to 30 V)		80	100		dB

1. Guaranteed by design and/or characterization.

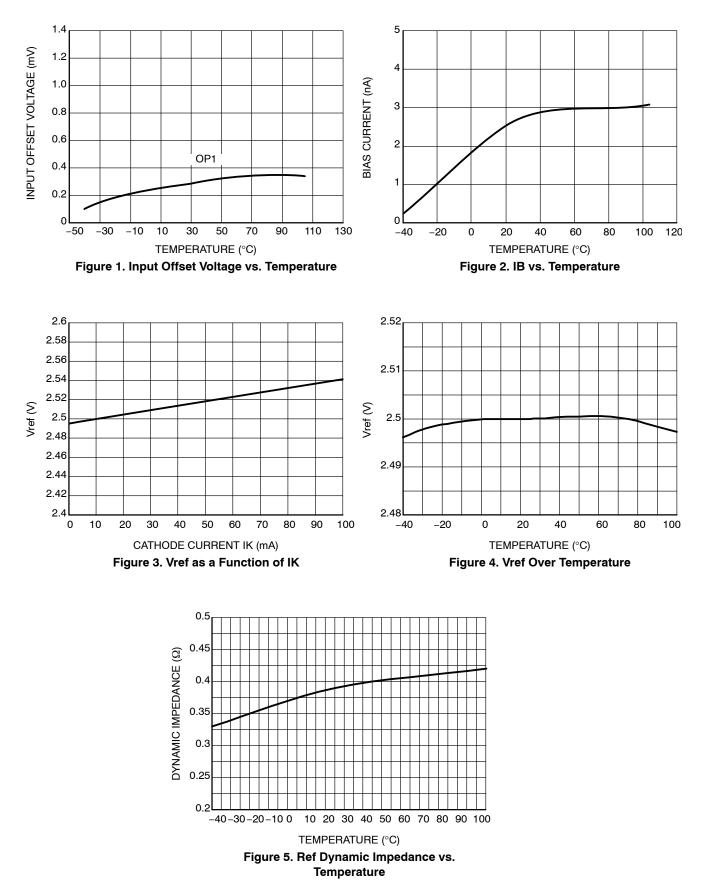
### **ELECTRICAL CHARACTERISTICS (continued)**

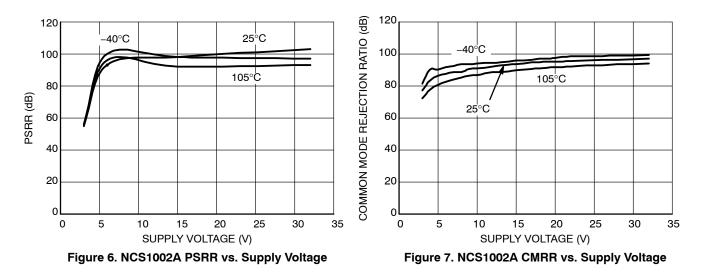
Symbol	Characteristics	Conditions	Min	Тур	Max	Unit		
<b>OP AMP 2 (INDEPENDENT OP AMP)</b> (continued) ( $V_{CC}$ = 5.0 V, $T_A$ = 25°C unless otherwise noted)								
V <sub>ICM</sub>	Input Common Mode Voltage Range (Note 2) (V <sub>CC</sub> = +30 V)	T <sub>A</sub> = 25°C	0		V <sub>CC</sub> – 1.5	V		
		$-40 \le T_A \le +105^{\circ}C$	0		V <sub>CC</sub> - 2.0			
CMRR	Common Mode Rejection Ratio (Note 4)	0 to V <sub>CC</sub> – 1.7 V, T <sub>A</sub> = 25°C	70	85		dB		
		0 to V <sub>CC</sub> - 2.2 V -40 $\leq$ T <sub>A</sub> $\leq$ +105°C	60					
ISOURCE	Output Current Source ( $V_{CC}$ = 15 V, $V_{OUT}$ = 2 V, V	I <sub>D</sub> = +1 V)	20	40		mA		
Ι <sub>Ο</sub>	Short–Circuit to GND (V <sub>CC</sub> = 15 V)			40	60	mA		
I <sub>SINK</sub>	Output Current Sink (V <sub>ID</sub> = -1 V)	$V_{CC}$ = +15 V, $V_{OUT}$ = 0.2 V	1	10		mA		
		V <sub>CC</sub> = +15 V, V <sub>OUT</sub> = 2 V	10	20		mA		
V <sub>OH</sub>	Output Voltage Swing, High ( $V_{CC} = 30 \text{ V}$ )	$R_L = 2 \text{ k}\Omega, T_A = 25^{\circ}C$	26	27		V		
		$-40 \le T_A \le +105^{\circ}C$	26					
		$R_L$ = 10 kΩ, $T_A$ = 25°C	27	28				
		$-40 \le T_A \le +105^{\circ}C$	27					
V <sub>OL</sub>	Output Voltage Swing, Low	R <sub>L</sub> = 10 kΩ, T <sub>A</sub> = 25°C		5.0	50	mV		
SR	Slew Rate (AV = +1, V <sub>i</sub> = 0.5 V to 3 V, V <sub>CC</sub> = 15 V, R <sub>L</sub> = 2 k $\Omega$ , C <sub>L</sub> = 100 pF)		0.2	0.4		V/μs		
GBP	Gain Bandwidth Product (V <sub>CC</sub> = 30 V, AV = +1, R <sub>L</sub> = 2 k $\Omega$ , C <sub>L</sub> = 100 pF, f = 100 kHz, V <sub>IN</sub> = 10 mV <sub>PP</sub> ) (Note 4)		0.5	0.9		MHz		
THD	Total Harmonic Distortion (f = 1 kHz, AV = 10, R <sub>L</sub> = 2 k $\Omega$ , V <sub>CC</sub> = 30 V, V <sub>OUT</sub> = 2 V <sub>PP</sub> )			0.08		%		
e <sub>noise</sub>	Equivalent Input Noise Voltage (f = 1 kHz, R <sub>S</sub> = 10	0 Ω, V <sub>CC</sub> = 30 V)		50		nV/√ <del>Hz</del>		

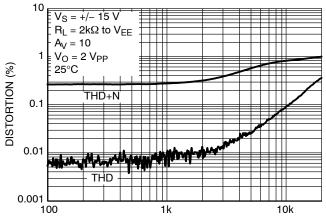
**VOLTAGE REFERENCE** (V<sub>CC</sub> = 5.0 V, T<sub>A</sub> = 25°C unless otherwise noted)

١ <sub>K</sub>	Cathode Current		0.05		100	mA
V <sub>ref</sub>	Reference Voltage (I <sub>K</sub> = 1 mA) $T_A = 25^{\circ}C$		2.49	2.5	2.51	V
		$-40 \le T_A \le +105^{\circ}C$	2.48	2.5	2.52	
$\Delta V_{ref}$	Reference Deviation over Temperature (V_{KA} = V_{ref}, I_K = 10 mA, -40 $\leq$ T_A $\leq$ +105°C) (Note 4)			7.0	30	mV
I <sub>min</sub>	Minimum Cathode Current for Regulation (2.4875 $V_f \leq V_{KA} \leq 2.5125 \; V_f)$			10	50	μΑ
I ZKA I	Dynamic Impedance (Note 3) (V <sub>KA</sub> = V <sub>ref</sub> , I <sub>K</sub> = 1 mA to 100 mA, f < 1 kHz)			0.2	0.5	Ω

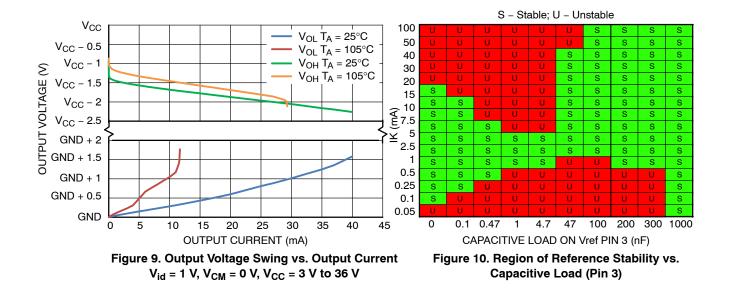
The input common-mode voltage of either input signal should not be allowed to go negative by more than 0.3 V. The upper end of the common-mode range is V<sub>CC</sub> - 1.5 V. Both inputs can go to V<sub>CC</sub> + 0.3 V without damage.
The Dynamic Impedance is defined as I ZKA I = ΔV<sub>KA</sub> / ΔI<sub>K</sub>.
Guaranteed by design and/or characterization.







FREQUENCY (Hz) Figure 8. Distortion vs. Frequency



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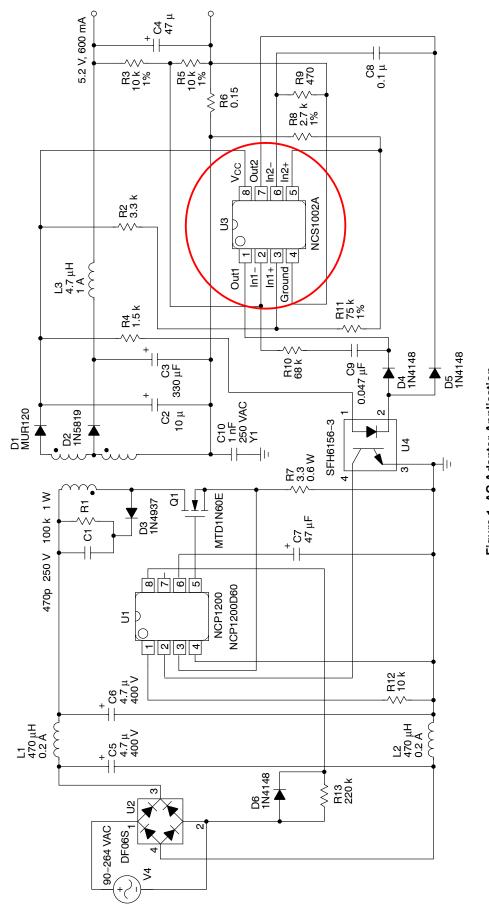


Figure 1. AC Adapter Application

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NCS1002ADR2G	SOIC-8 (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

### STYLES ON PAGE 2

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STYLE 1: PIN 1. EMITTER COLLECTOR 2. 3. COLLECTOR 4. EMITTER 5. EMITTER BASE 6. 7 BASE EMITTER 8. STYLE 5: PIN 1. DRAIN 2. DRAIN 3. DRAIN DRAIN 4. GATE 5. 6. GATE SOURCE 7. 8. SOURCE STYLE 9: PIN 1. EMITTER, COMMON COLLECTOR, DIE #1 COLLECTOR, DIE #2 2. З. EMITTER, COMMON 4. 5. EMITTER, COMMON 6 BASE. DIE #2 BASE, DIE #1 7. 8. EMITTER, COMMON STYLE 13: PIN 1. N.C. 2. SOURCE 3 GATE 4. 5. DRAIN 6. DRAIN DRAIN 7. DRAIN 8. STYLE 17: PIN 1. VCC 2. V2OUT V10UT З. TXE 4. 5. RXE 6. VFF 7. GND 8. ACC STYLE 21: PIN 1. CATHODE 1 2. CATHODE 2 3 CATHODE 3 CATHODE 4 4. 5. CATHODE 5 6. COMMON ANODE COMMON ANODE 7. 8. CATHODE 6 STYLE 25: PIN 1. VIN 2 N/C REXT З. 4. GND 5. IOUT IOUT 6. IOUT 7. 8. IOUT STYLE 29: BASE, DIE #1 PIN 1. 2 EMITTER, #1 BASE, #2 З. EMITTER, #2 4. 5 COLLECTOR, #2 COLLECTOR, #2 6.

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 COLLECTOR, #2 3. COLLECTOR, #2 4 BASE, #2 5. EMITTER, #2 6. 7 BASE #1 EMITTER, #1 8. STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN SOURCE 4. SOURCE 5. 6. GATE GATE 7. 8. SOURCE STYLE 10: GROUND PIN 1. BIAS 1 OUTPUT 2. З. GROUND 4. 5. GROUND 6 BIAS 2 INPUT 7. 8. GROUND STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3 P-SOURCE P-GATE 4. P-DRAIN 5 6. P-DRAIN N-DRAIN 7. N-DRAIN 8. STYLE 18: PIN 1. ANODE ANODE 2. SOURCE 3. GATE 4. 5. DRAIN 6 DRAIN CATHODE 7. 8. CATHODE STYLE 22 PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3 COMMON CATHODE/VCC 4. I/O LINE 3 COMMON ANODE/GND 5. 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND STYLE 26: PIN 1. GND 2 dv/dt З. ENABLE 4. ILIMIT 5. SOURCE SOURCE 6. SOURCE 7. 8. VCC STYLE 30: DRAIN 1 PIN 1. DRAIN 1 2 GATE 2 З. SOURCE 2 4 SOURCE 1/DRAIN 2 SOURCE 1/DRAIN 2 5. 6.

7.

8. GATE 1

SOURCE 1/DRAIN 2

STYLE 3: PIN 1. DRAIN, DIE #1 DRAIN, #1 2. DRAIN, #2 З. DRAIN, #2 4. 5. GATE, #2 SOURCE, #2 6. 7 GATE #1 8. SOURCE, #1 STYLE 7: PIN 1. INPUT 2. EXTERNAL BYPASS THIRD STAGE SOURCE GROUND З. 4. 5. DRAIN 6. GATE 3 SECOND STAGE Vd 7. FIRST STAGE Vd 8. STYLE 11: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. З. GATE 2 4. 5. DRAIN 2 6. DRAIN 2 DRAIN 1 7. 8. DRAIN 1 STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3 ANODE 1 ANODE 1 4. 5. CATHODE, COMMON CATHODE, COMMON CATHODE, COMMON 6. 7. CATHODE, COMMON 8. STYLE 19: PIN 1. SOURCE 1 GATE 1 SOURCE 2 2. 3. GATE 2 4. 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 MIRROR 1 8. STYLE 23: PIN 1. LINE 1 IN COMMON ANODE/GND COMMON ANODE/GND 2. 3 LINE 2 IN 4. LINE 2 OUT 5. COMMON ANODE/GND COMMON ANODE/GND 6. 7. 8. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 2 OVI 0 З. UVLO 4. INPUT+ 5. 6. SOURCE SOURCE SOURCE 7. 8 DRAIN

#### DATE 16 FEB 2011

STYLE 4: ANODE PIN 1. ANODE 2. ANODE З. 4. ANODE ANODE 5. 6. ANODE 7 ANODE COMMON CATHODE 8. STYLE 8: PIN 1. COLLECTOR, DIE #1 2. BASE, #1 BASE #2 З. COLLECTOR, #2 4. COLLECTOR, #2 5. 6. EMITTER, #2 EMITTER, #1 7. 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE SOURCE 2. 3. GATE 4. 5. DRAIN 6 DRAIN DRAIN 7. 8. DRAIN STYLE 16 EMITTER, DIE #1 PIN 1. 2. BASE, DIE #1 EMITTER DIE #2 3 BASE, DIE #2 4. 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 COLLECTOR, DIE #1 7. COLLECTOR, DIE #1 8. STYLE 20: PIN 1. SOURCE (N) GATE (N) SOURCE (P) 2. 3. 4. GATE (P) 5. DRAIN 6. DRAIN DRAIN 7. 8. DRAIN STYLE 24: PIN 1. BASE EMITTER 2. 3 COLLECTOR/ANODE COLLECTOR/ANODE 4. 5. CATHODE 6. CATHODE COLLECTOR/ANODE 7. COLLECTOR/ANODE 8. STYLE 28: 11. SW\_TO\_GND 2. DASIC OFF PIN 1. DASIC\_SW\_DET З. 4. GND 5. 6. V MON VBULK 7. VBULK 8 VIN

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COLLECTOR, #1

COLLECTOR, #1

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